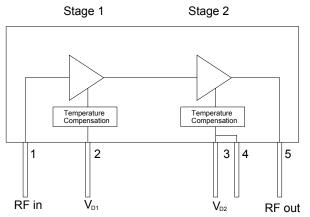


Product Description

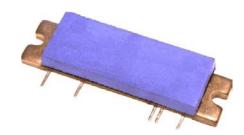
Sirenza Microdevices' XD010-22S-D2F 12W power module is a robust 2stage Class A/AB amplifier module for use in the driver stages of GSM/ EDGE RF power amplifiers for cellular base stations. The power transistors are fabricated using Sirenza's latest, high performance LDMOS process. This unit operates from a single voltage and has internal temperature compensation of the bias voltage to ensure stable performance over the full temperature range. It is a drop-in, no-tune solution for medium power applications requiring high efficiency, excellent linearity, and unit-to-unit repeatability. It is internally matched to 50 ohms.

Functional Block Diagram



Case Flange = Ground

XD010-22S-D2F 1805-1880 MHz Class A/AB **12W Power Amplifier Module**



Product Features

- 50 Ω RF impedance
- 12W Output P_{1dB}
- Single Supply Operation : Nominally 28V
- High Gain: 31 dB at 1840 MHz
- High Efficiency: 25% at 1840 MHz
- Advanced, XeMOS II LDMOS FETS
- Temperature Compensation

Applications

- **Base Station PA driver**
- Repeater
- GSM / EDGE

Symbol	Parameter	Unit	Min.	Тур.	Max.
Frequency	Frequency of Operation	MHz	1805		1880
P _{1dB}	Output Power at 1dB Compression (single tone)	W	10	12	
Gain	Gain at 5W Output Power (CW)	dB	28.5	31	
Gain Flatness	Peak to Peak Gain Variation	dB		0.5	1.0
IRL	Input Return Loss 5W Output (CW)	dB	10	14	
Efficiency	Drain Efficiency at 10W CW	%	20	25	
	RMS EVM at 5W EDGE output	%		1.5	
Linearity	Peak EVM at 5W EDGE output	%		5	
	3 rd Order IMD at 10W PEP (Two Tone; 1MHz ∆F)	dBc	-26	-32	
Delay	Electrical Delay	nS		2.5	
Phase Linearity	Deviation from Linear Phase (Peak to Peak)	Deg		0.5	
R _{TH, j-I}	Thermal Resistance Stage 1 (Junction to Case)	°C/W		11	
R _{TH, j-2}	Thermal Resistance Stage 2 (Junction to Case)	°C/W		4	

The information provided herein is believed to be reliable at oress time. Sirenza Microdevices assumes no responsibility for inaccuracies or omissions, Sirenza Microdevices assumes no responsibility for the use of this information, and all such The information provided network to be reliable at pless line. One reliable at pless line is a statistication and a statistication and

Key Specifications



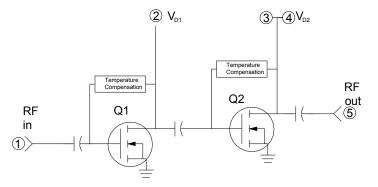
Quality Specifications

	Parameter		Unit	Typical
Γ	ESD Rating	Human Body Model, JEDEC Document - JESD22-A114-B	V	8000
	MTTF	85°C Leadframe, 200°C Channel	Hours	1.2 X 10 ⁶

Pin Description

Pin #	Function	Description	
1	RF Input	Module RF input. Care must be taken to protect against video transients that may damage the active devices.	
2 V _{D1} This is the drain voltage for the first stage of the amplifier module. Th maintain constant quiscent drain current over the operating temperat		This is the drain voltage for the first stage of the amplifier module. The first stage gate bias is temperature compensated to maintain constant quiscent drain current over the operating temperature range. Nominally +28Vdc See Note 1.	
3,4	V _{D2}	This is the drain voltage for the 2 nd stage of the amplifier module. The 2 nd stage gate bias is temperature compensated to maintain constant quiscent drain current over the operating temperature range. Nominally +28Vdc See Note 1.	
5	RF Output	Module RF output. Care must be taken to protect against video transients that may damage the active devices.	
Flange	Gnd	Exposed area on the bottom side of the package needs to be mechanically attached to the ground plane of the board for optimum thermal and RF performance. See mounting instructions in application note AN-060 on Sirenza's web site.	

Simplified Device Schematic



Case Flange = Ground

Absolute Maximum Ratings

Parameters	Value	Unit		
1 st Stage Bias Voltage (V _{D1})	35	V		
2 nd Stage Bias Voltage (V _{D2})	35	V		
RF Input Power	+20	dBm		
Load Impedance for Continuous Operation With- out Damage	5:1	VSWR		
Output Device Channel Temperature	+200	°C		
Operating Temperature Range	-20 to +90	°C		
Storage Temperature Range	-40 to +100	°C		
Operation of this device beyond any one of these limits may cause per- manent damage. For reliable continuous operation see typical setup val-				

ues specified in the table on page one.

Note 1:

The internally generated gate voltage is thermally compensated to maintain constant quiescent current over the temperature range listed in the data sheet. No compensation is provided for gain changes with temperature. This can only be accomplished with AGC external to the module.

Note 2:

Internal RF decoupling is included on all bias leads. No additional bypass elements are required, however some applications may require energy storage on the drain leads to accommodate time-varying waveforms.

Note 3:

This module was designed to have its leads hand soldered to an adjacent PCB. The maximum soldering iron tip temperature should not exceed 700° C, and the soldering iron tip should not be in direct contact with the lead for longer than 10 seconds. Refer to app note AN060 (www.sirenza.com) for further installation instructions.



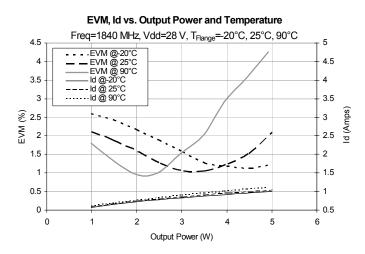
Caution: ESD Sensitive

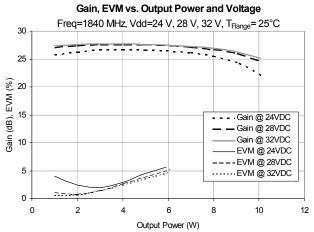
Appropriate precaution in handling, packaging and testing devices must be observed.

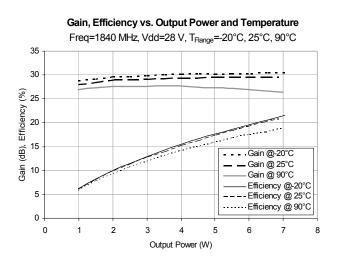
303 S. Technology Court Broomfield, CO 80021 http://www.sirenza.com EDS-102930 Rev C

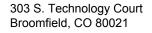


Typical Performance Curves

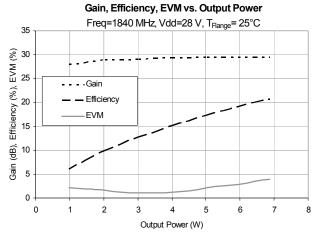


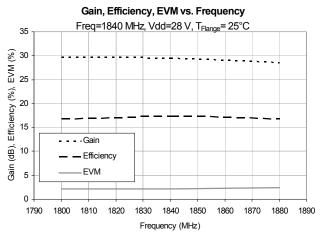


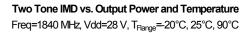


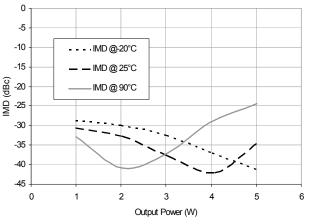


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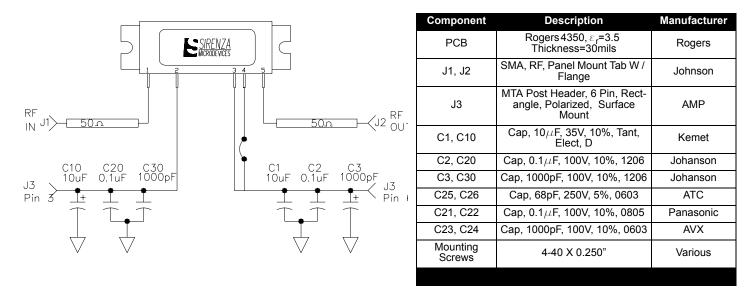




http://www.sirenza.com EDS-102930 Rev C

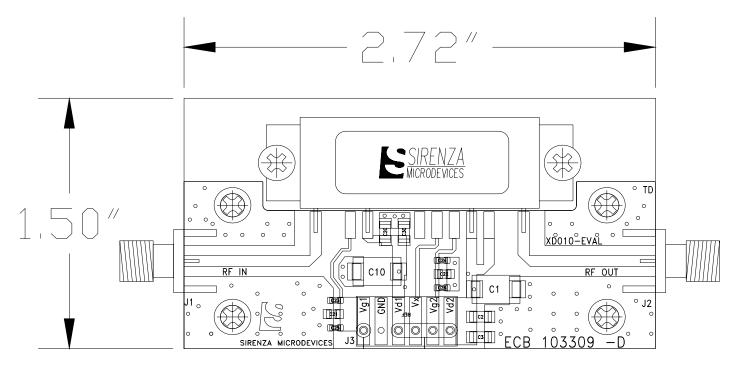


Test Board Schematic with module attachments shown



Test Board Bill of Materials

Test Board Layout

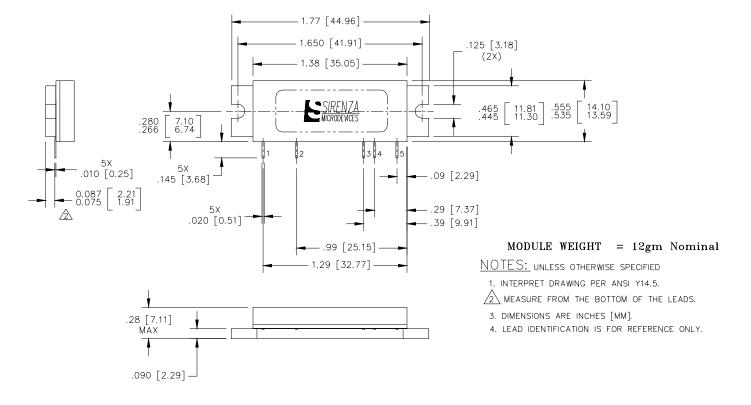


To receive Gerber files, DXF drawings, a detailed BOM, and assembly recommendations for the test board with fixture, contact applications support at support@sirenza.com. Data sheet for evaluation circuit (XD010-EVAL) available from Sirenza website.

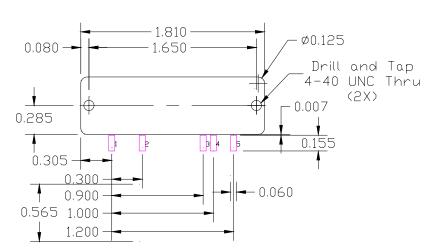
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Package Outline Drawing



Recommended PCB Cutout and Landing Pads for the D2F Package



Note 3: Dimensions are in inches

Refer to Application note AN-060 "Installation Instructions for XD Module Series" for additional mounting info. App note available at at www.sirenza.com

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